

SINGLE 5-Ω SP3T ANALOG SWITCH 5-V/3.3-V 3:1 MULTIPLEXER/DEMULTIPLEXER

Check for Samples: [TS5A3357-Q1](#)

FEATURES

- Qualified for Automotive Applications
- Specified Break-Before-Make Switching
- Low ON-State Resistance
- High Bandwidth
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch Up Exceeds 100 mA per JESD78B, Class I

DESCRIPTION/ORDERING INFORMATION

The TS5A3357 is a high-performance, single-pole triple throw (SP3T) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and low input/output capacitance and, thus, causes a very low signal distortion. The break-before-make feature allows transferring of a signal from one port to another, with a minimal signal distortion. This device also offers a low charge injection which makes this device suitable for high-performance audio and data acquisition systems.

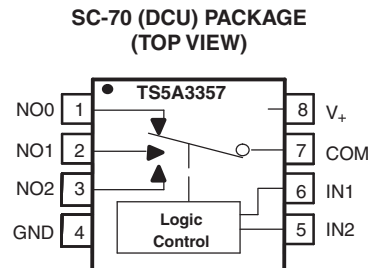


Table 1. Summary of Characteristics⁽¹⁾

Configuration	Triple 3:1 Multiplexer/ Demultiplexer (1 × SP3T)
Number of channels	1
ON-state resistance (r_{on})	5 Ω
ON-state resistance match (Δr_{on})	0.1 Ω
ON-state resistance flatness ($r_{on(Flat)}$)	6.5 Ω
Turn-on/turn-off time (t_{ON}/t_{OFF})	6.5 ns/3.7 ns
Break-before-make time (t_{BBM}) ⁽²⁾	0.5 ns
Charge injection (Q_C)	3.4 pC
Bandwidth (BW)	334 MHz
OFF isolation (O_{ISO})	-82 dB at 10 MHz
Crosstalk (X_{TALK})	-62 dB at 10 MHz
Total harmonic distortion (THD)	0.05%
Leakage current ($I_{COM(OFF)}$)	±1 μA
Package option	8-pin DCU (US8)

(1) $V_+ = 5\text{ V}$, $T_A = 25^\circ\text{C}$

(2) Specified by designed. Not production tested.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Table 2. FUNCTION TABLE

IN1	IN2	COM TO NO0	COM TO NO1	COM TO NO2
L	L	OFF	OFF	OFF
H	L	ON	OFF	OFF
L	H	OFF	ON	OFF
H	H	OFF	OFF	ON

Table 3. ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOT – DCU	Reel of 3000	TS5A3357QDCURQ1	JAVR

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

ABSOLUTE MINIMUM AND MAXIMUM RATINGS^{(1) (2)}

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾	–0.5	6.5	V
V _{NO} V _{COM}	Analog voltage range ^{(3) (4) (5)}	–0.5	V ₊ + 0.5	V
I _K	Analog port diode current	V _{NO} , V _{COM} < 0 or V _{NO} , V _{COM} > V ₊		mA
I _{NO} I _{COM}	On-state switch current	V _{NO} , V _{COM} = 0 to V ₊		mA
V _I	Digital input voltage range ^{(3) (4)}	–0.5	6.5	V
I _{IK}	Digital input clamp current	V _I < 0		mA
I ₊	Continuous current through V ₊		100	mA
I _{GND}	Continuous current through GND	–100	100	mA
T _{stg}	Storage temperature range	–65	150	°C

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.

PACKAGE THERMAL IMPEDANCE

		MAX	UNIT
θ _{JA}	Package thermal impedance ⁽¹⁾	165	°C/W

- (1) The package thermal impedance is calculated in accordance with JESD 51-7.

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY⁽¹⁾
 $V_+ = 4.5\text{ V to }5.5\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch								
Analog signal range	V_{COM}, V_{NO}				0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -30\text{ mA}$, Switch ON, See Figure 13	Full	4.5 V			15	Ω
ON-state resistance	r_{on}	$V_{NO} = 0$, $I_{COM} = 30\text{ mA}$	25°C	4.5 V		5	7	Ω
			Full				7	
		25°C			6	12		
		Full				12		
		25°C			7	15		
		$V_{NO} = 4.5\text{ V}$, $I_{COM} = -30\text{ mA}$	Full				15	
ON-state resistance match between channels	Δr_{on}	$V_{NO} = 3.15\text{ V}$, $I_{COM} = -30\text{ mA}$, Switch ON, See Figure 13	25°C	4.5 V		0.1		Ω
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -30\text{ mA}$, Switch ON, See Figure 13	25°C	5 V		6.5		Ω
NO OFF leakage current	$I_{NO(OFF)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = V_+\text{ to }0$, Switch OFF, See Figure 14	25°C	5.5 V	-0.2		0.2	μA
			Full		-1		1	
COM OFF leakage current	$I_{COM(OFF)}$	$V_{COM} = 0\text{ to }V_+$, $V_{NO} = V_+\text{ to }0$, Switch OFF, See Figure 14	25°C	0	-0.2		0.2	μA
			Full		-1		1	
NO ON leakage current	$I_{NO(ON)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = \text{Open}$, Switch ON, See Figure 14	25°C	5.5 V	-0.2		0.2	μA
			Full		-1		1	
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} = \text{Open}$, $V_{COM} = 0\text{ to }V_+$, Switch ON, See Figure 14	25°C	5.5 V	-0.2		0.2	μA
			Full		-1		1	
Digital Control Inputs (IN1, IN2)⁽²⁾								
Input logic high	V_{IH}		Full		$V_+ \times 0.7$		5.5	V
Input logic low	V_{IL}		Full		0		$V_+ \times 0.3$	V
Input leakage current	I_{IH}, I_{IL}	$V_I = 5.5\text{ V or }0$	25°C	5.5 V			0.1	μA
			Full				1	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY ⁽¹⁾ (continued)
 $V_+ = 4.5\text{ V to }5.5\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$, See Figure 16	25°C	5 V	1.5		10	ns
			Full	4.5 V to 5.5 V	1.5		10	
Turn-off time	t_{OFF}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$, See Figure 16	25°C	5 V	0.8		6.5	ns
			Full	4.5 V to 5.5 V	0.8		7	
Break-before-make time ⁽³⁾	t_{BBM}	$V_{NO} = V_+$, $R_L = 50\ \Omega$, See Figure 17	25°C	5 V	0.5			ns
			Full	4.5 V to 5.5 V	0.5			
Charge injection	Q_C	$V_{GEN} = 0$, $C_L = 0.1\text{ nF}$, See Figure 21	25°C	5 V		3.4		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15	25°C	5 V		4.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15	25°C	5 V		10.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON, See Figure 15	25°C	5 V		17		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON, See Figure 15	25°C	5 V		17		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND, See Figure 15	25°C	5 V		3		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch ON, See Figure 18	25°C	4.5 V to 5.5 V		334		MHz
OFF isolation	O_{ISO}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch OFF, See Figure 19	25°C	4.5 V to 5.5 V		-82		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch ON, See Figure 20	25°C	4.5 V to 5.5 V		-62		dB
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF	25°C	5.5 V			1	μA
			Full				10	

(3) Specified by designed. Not production tested.

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾
 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT	
Analog Switch									
Analog signal range	V_{COM}, V_{NO}				0		V_+	V	
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -24\text{ mA}$, Switch ON, See Figure 13	Full	3 V			25	Ω	
ON-state resistance	r_{on}	$V_{NO} = 0\text{ V}$, $I_{COM} = 24\text{ mA}$ Switch ON, See Figure 13	25°C	3 V			6.5	9	Ω
			Full				9		
			25°C				9	20	
			Full				20		
ON-state resistance match between channels	Δr_{on}	$V_{NO} = 2.1\text{ V}$, $I_{COM} = -24\text{ mA}$, Switch ON, See Figure 13	25°C	3 V		0.1		Ω	
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -24\text{ mA}$, Switch ON, See Figure 13	25°C	3.3 V		13.5		Ω	
NO OFF leakage current	$I_{NO(OFF)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = V_+\text{ to }0$, Switch OFF, See Figure 14	25°C	3.6 V			-0.2	0.2	μA
			Full				-1	1	
COM OFF leakage current	$I_{COM(OFF)}$	$V_{COM} = 0\text{ to }V_+$, $V_{NO} = V_+\text{ to }0$, Switch OFF, See Figure 14	25°C	3.6 V			-0.2	0.2	μA
			Full				-1	1	
NO ON leakage current	$I_{NO(ON)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = V_+\text{ to }0$, Switch ON, See Figure 14	25°C	3.6 V			-0.2	0.2	μA
			Full				-1	1	
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} = \text{Open}$, $V_{COM} = 0\text{ to }V_+$, Switch ON, See Figure 14	25°C	3.6 V			-0.2	0.2	μA
			Full				-1	1	
Digital Control Inputs (IN1, IN2)⁽²⁾									
Input logic high	V_{IH}		Full				$V_+ \times 0.7$	5.5	V
Input logic low	V_{IL}		Full			0		$V_+ \times 0.3$	V
Input leakage current	I_{IH}, I_{IL}	$V_I = 5.5\text{ V or }0$	25°C	3.6 V			-1	0.1	μA
			Full					1	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY ⁽¹⁾ (continued)
 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$,	$C_L = 50\text{ pF}$, See Figure 16	25°C	3.3 V	2	12	ns
				Full	3 V to 3.6 V	2	12.9	
Turn-off time	t_{OFF}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$,	$C_L = 50\text{ pF}$, See Figure 16	25°C	3.3 V	1.3	8	ns
				Full	3 V to 3.6 V	1.5	8	
Break-before-make time ⁽³⁾	t_{BBM}	$V_{NO} = V_+$, $R_L = 50\ \Omega$,	$C_L = 50\text{ pF}$, See Figure 17	25°C	3.3 V	0.5		ns
				Full	3 V to 3.6 V	0.5		
Charge injection	Q_C	$V_{GEN} = 0$, $C_L = 0.1\text{ nF}$,	25°C	3.3 V		1.75		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	25°C	3.3 V		4.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	25°C	3.3 V		10.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	25°C	3.3 V		17		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	25°C	3.3 V		17		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	25°C	3.3 V		3		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch ON,	25°C	3 V to 3.6 V		327		MHz
OFF isolation	O_{ISO}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$,	25°C	3 V to 3.6 V		-82		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$,	25°C	3 V to 3.6 V		-62		dB
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	3.6 V		1	μA
				Full			10	

(3) Specified by designed. Not production tested.

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾
 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT	
Analog Switch									
Analog signal range	V_{COM}, V_{NO}				0		V_+	V	
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 13	Full	2.3 V			50	Ω	
ON-state resistance	r_{on}	$V_{NO} = 0 \text{ V}$, $I_{COM} = 8 \text{ mA}$ $V_{NO} = 2.3 \text{ V}$, $I_{COM} = -8 \text{ mA}$	Switch ON, See Figure 13	25°C	2.3 V		8	12	Ω
				Full			12		
				25°C			11	30	
				Full			30		
ON-state resistance match between channels	Δr_{on}	$V_{NO} = 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 13	25°C	2.3 V		0.3		Ω	
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 13	25°C	2.5 V		39		Ω	
NO OFF leakage current	$I_{NO(OFF)}$	$V_{NO} = 0 \text{ to } V_+$, $V_{COM} = V_+ \text{ to } 0$, Switch OFF, See Figure 14	25°C	2.7 V	-0.2		0.2	μA	
			Full		-1	1			
COM OFF leakage current	$I_{COM(OFF)}$	$V_{COM} = 0 \text{ to } V_+$, $V_{NO} = V_+ \text{ to } 0$, Switch OFF, See Figure 14	25°C	2.7 V	-0.2		0.2	μA	
			Full		-1	1			
NO ON leakage current	$I_{NO(ON)}$	$V_{NO} = 0 \text{ to } V_+$, $V_{COM} = V_+ \text{ to } 0$, Switch ON, See Figure 14	25°C	2.7 V	-0.2		0.2	μA	
			Full		-1	1			
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} = \text{Open}$, $V_{COM} = 0 \text{ to } V_+$, Switch ON, See Figure 14	25°C	2.7 V	-0.2		0.2	μA	
			Full		-1	1			
Digital Control Inputs (IN1, IN2)⁽²⁾									
Input logic high	V_{IH}		Full		$V_+ \times 0.75$		5.5	V	
Input logic low	V_{IL}		Full		0		$V_+ \times 0.25$	V	
Input leakage current	I_{IH}, I_{IL}	$V_I = 5.5 \text{ V or } 0$	25°C	2.7 V			0.1	μA	
			Full			1			

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY ⁽¹⁾ (continued)
 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{NO} = V_+$ or GND, $R_L = 500 \Omega$, $C_L = 50 \text{ pF}$, See Figure 16		25°C	2.5 V	3	15	ns
				Full	2.3 V to 2.7 V	3	19.4	
Turn-off time	t_{OFF}	$V_{NO} = V_+$ or GND, $R_L = 500 \Omega$, $C_L = 50 \text{ pF}$, See Figure 16		25°C	2.5 V	2	8.1	ns
				Full	2.3 V to 2.7 V	2	10	
Break-before-make time ⁽³⁾	t_{BBM}	$V_{NO} = V_+$, $R_L = 50 \Omega$, $C_L = 50 \text{ pF}$, See Figure 17		25°C	2.5 V	0.5		ns
				Full	2.3 V to 2.7 V	0.5		
Charge injection	Q_C	$V_{GEN} = 0$, $C_L = 0.1 \text{ nF}$, See Figure 21		25°C	2.5 V	1.15		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15		25°C	2.5 V	4.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15		25°C	2.5 V	10.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON, See Figure 15		25°C	2.5 V	17		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON, See Figure 15		25°C	2.5 V	17		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND, See Figure 15		25°C	2.5 V	3		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON, See Figure 18		25°C	2.3 V to 2.7 V	320		MHz
OFF isolation	O_{ISO}	$R_L = 50 \Omega$, $f = 10 \text{ MHz}$, Switch OFF, See Figure 19		25°C	2.3 V to 2.7 V	-81		dB
Crosstalk	X_{TALK}	$R_L = 50 \Omega$, $f = 10 \text{ MHz}$, Switch ON, See Figure 20		25°C	2.3 V to 2.7 V	-61		dB
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF		25°C	2.7 V		1	μA
				Full		10		

(3) Specified by design. Not production tested.

ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY⁽¹⁾
 $V_+ = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT	
Analog Switch									
Analog signal range	V_{COM}, V_{NO}				0		V_+	V	
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -4\text{ mA}$, Switch ON, See Figure 13	Full	1.65 V			150	Ω	
ON-state resistance	r_{on}	$V_{NO} = 0\text{ V}$, $I_{COM} = 4\text{ mA}$ $V_{NO} = 1.8\text{ V}$, $I_{COM} = -4\text{ mA}$	Switch ON, See Figure 13	25°C	1.65 V		10	20	Ω
				Full			20		
				25°C			17	50	
				Full			50		
ON-state resistance match between channels	Δr_{on}	$V_{NO} = 1.15\text{ V}$, $I_{COM} = -4\text{ mA}$, Switch ON, See Figure 13	25°C	1.65 V		0.3		Ω	
ON-state resistance flatness	$r_{on(flat)}$	$0 \leq V_{NO} \leq V_+$, $I_{COM} = -4\text{ mA}$, Switch ON, See Figure 13	25°C	1.8 V		140		Ω	
NO OFF leakage current	$I_{NO(OFF)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = V_+ \text{ to } 0$, Switch OFF, See Figure 14	25°C	1.95 V	-0.2		0.2	μA	
			Full		-1	1			
COM OFF leakage current	$I_{COM(OFF)}$	$V_{COM} = 0\text{ to }V_+$, $V_{NO} = V_+ \text{ to } 0$, Switch OFF, See Figure 14	25°C	1.95 V	-0.2		0.2	μA	
			Full		-1	1			
NO ON leakage current	$I_{NO(ON)}$	$V_{NO} = 0\text{ to }V_+$, $V_{COM} = V_+ \text{ to } 0$, Switch ON, See Figure 14	25°C	1.95 V	-0.2		0.2	μA	
			Full		-1	1			
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} = \text{Open}$, $V_{COM} = 0\text{ to }V_+$, Switch ON, See Figure 14	25°C	1.95 V	-0.2		0.2	μA	
			Full		-1	1			
Digital Control Inputs (IN1, IN2)⁽²⁾									
Input logic high	V_{IH}		Full		$V_+ \times 0.75$		5.5	V	
Input logic low	V_{IL}		Full		0		$V_+ \times 0.25$	V	
Input leakage current	I_{IH}, I_{IL}	$V_I = 5.5\text{ V or } 0$	25°C	1.95 V			0.1	μA	
			Full			1			

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY ⁽¹⁾ (continued)
 $V_+ = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$, $C_L = 50\text{ pF}$, See Figure 16	25°C	1.8 V	5		32	ns
			Full	1.65 V to 1.95 V	5		40	
Turn-off time	t_{OFF}	$V_{NO} = V_+$ or GND, $R_L = 500\ \Omega$, $C_L = 50\text{ pF}$, See Figure 16	25°C	1.8 V	3		14	ns
			Full	1.65 V to 1.95 V	3		17.6	
Break-before-make time ⁽³⁾	t_{BBM}	$V_{NO} = V_+$, $R_L = 50\ \Omega$, $C_L = 50\text{ pF}$, See Figure 17	25°C	1.8 V	0.5			ns
			Full	1.65 V to 1.95 V	0.5			
Charge injection	Q_C	$V_{GEN} = 0$, $C_L = 0.1\text{ nF}$, See Figure 21	25°C	1.8 V		0.3		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15	25°C	1.8 V		4.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF, See Figure 15	25°C	1.8 V		10.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON, See Figure 15	25°C	1.8 V		17		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON, See Figure 15	25°C	1.8 V		17		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND, See Figure 15	25°C	1.8 V		3		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch ON, See Figure 18	25°C	1.65 V to 1.95 V		341		MHz
OFF isolation	O_{ISO}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch OFF, See Figure 19	25°C	1.65 V to 1.95 V		-81		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch ON, See Figure 20	25°C	1.65 V to 1.95 V		-61		dB
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF	25°C	1.95 V			1	μA
			Full				10	

(3) Specified by designed. Not production tested.

TYPICAL PERFORMANCE

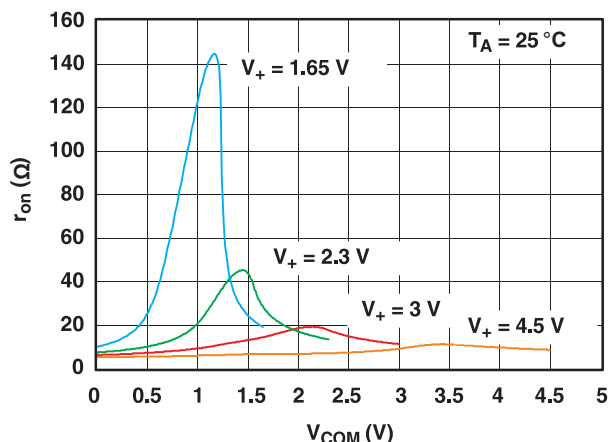


Figure 1. r_{on} vs V_{COM}

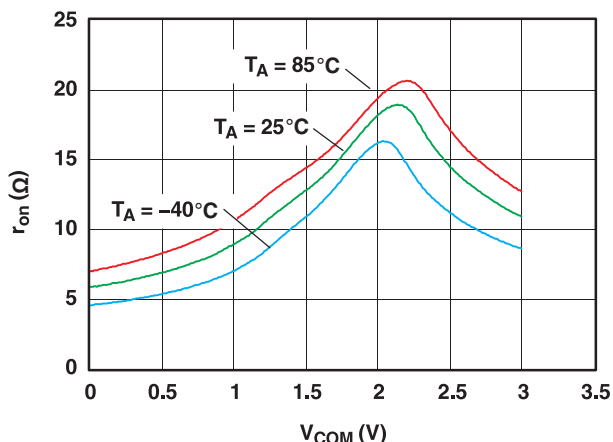


Figure 2. r_{on} vs V_{COM} ($V_+ = 3\text{ V}$)

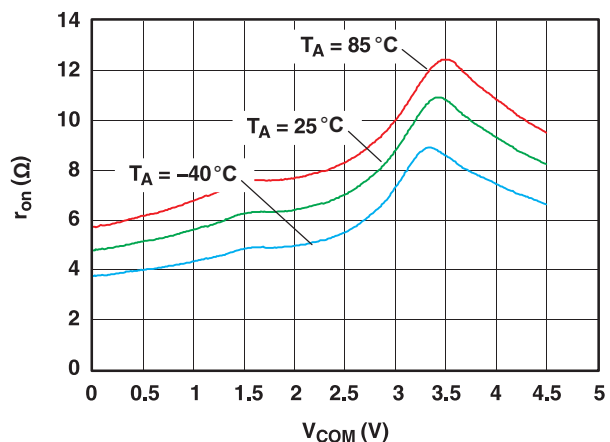


Figure 3. r_{on} vs V_{COM} ($V_+ = 4.5\text{ V}$)

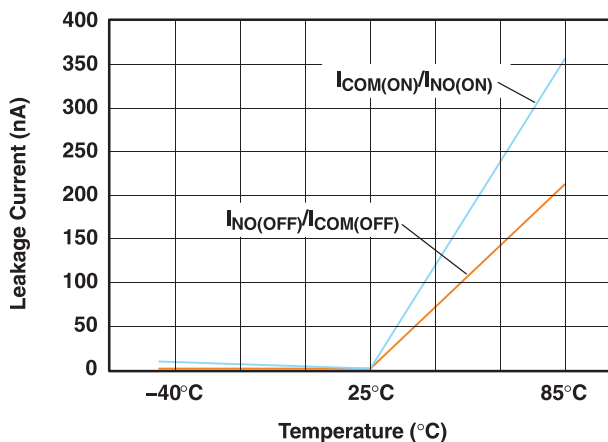


Figure 4. Leakage Current vs Temperature ($V_+ = 5.5\text{ V}$)

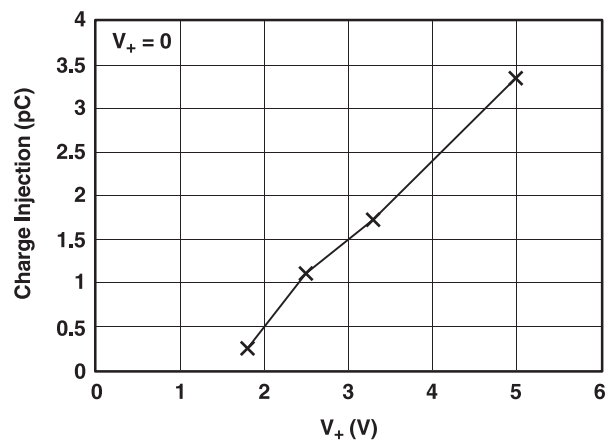


Figure 5. Charge Injection (Q_C) vs V_{COM}

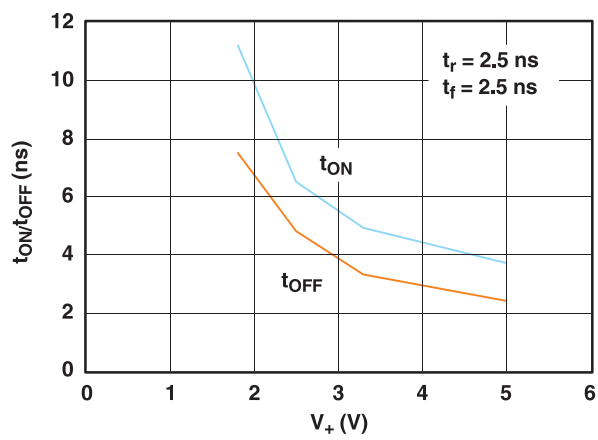


Figure 6. t_{ON} and t_{OFF} vs V_+

TYPICAL PERFORMANCE (continued)

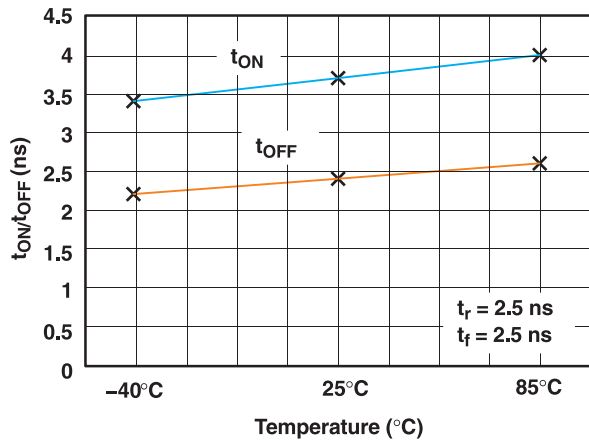


Figure 7. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

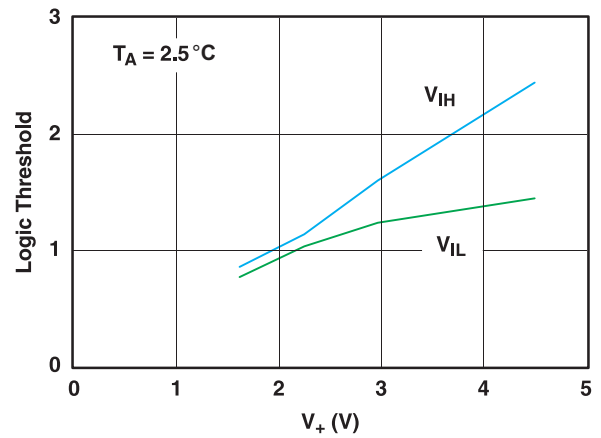


Figure 8. Logic-Level Threshold vs V₊

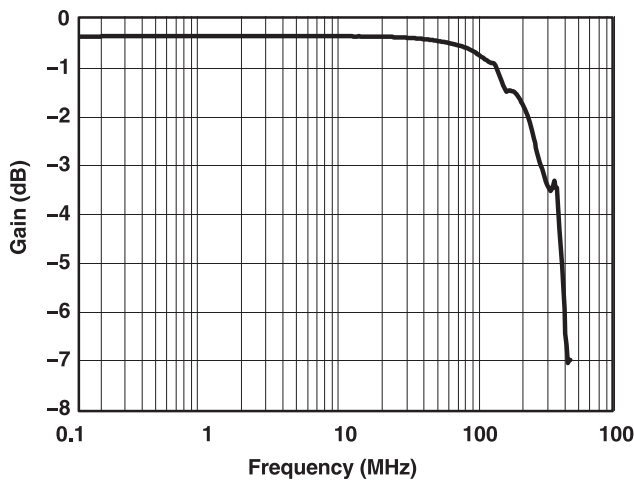


Figure 9. Frequency Response (V₊ = 3 V)

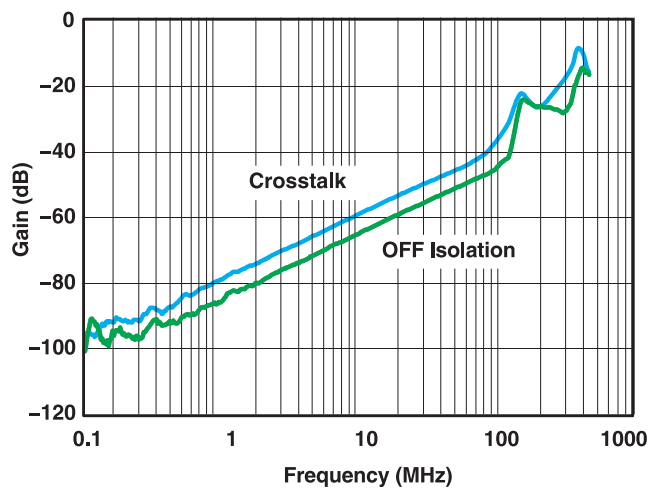


Figure 10. OFF Isolation and Crosstalk vs Frequency (V₊ = 3 V)

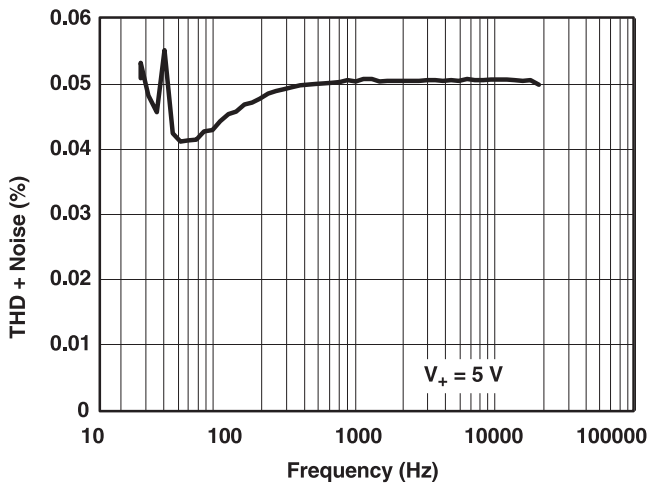


Figure 11. Total Harmonic Distortion vs Frequency (V₊ = 5 V)

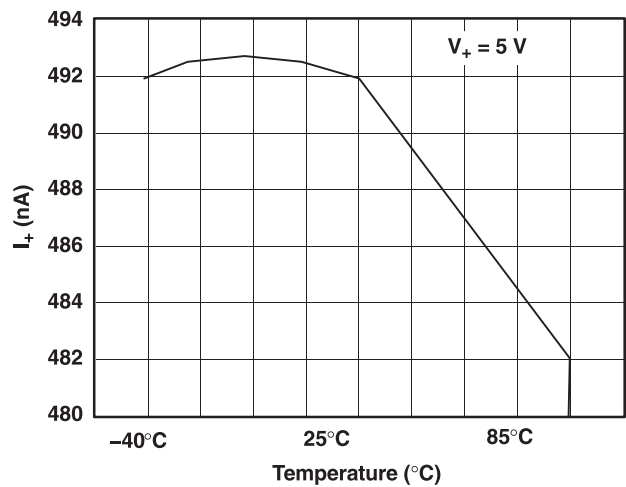


Figure 12. Power-Supply Current vs Temperature (V₊ = 5 V)

Table 4. PIN DESCRIPTION

PIN NO.	NAME	DESCRIPTION
1	NO0	Normally open
2	NO1	Normally open
3	NO2	Normally open
4	GND	Digital ground
5	IN2	Digital control to connect COM to NO
6	IN1	Digital control to connect COM to NO
7	COM	Common
8	V ₊	Power supply

Table 5. PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V _{COM}	Voltage at COM
V _{NO}	Voltage at NO
r _{on}	Resistance between COM and NC or COM and NO ports when the channel is ON
r _{peak}	Peak on-state resistance over a specified voltage range
Δr _{on}	Difference of r _{on} between channels in a specific device
r _{on(flat)}	Difference between the maximum and minimum value of r _{on} in a channel over the specified range of conditions
I _{NO(OFF)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
I _{NO(ON)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
I _{COM(ON)}	Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) open
I _{COM(OFF)}	Leakage current measured at the COM port during the power-down condition, V ₊ = 0
V _{IH}	Minimum input voltage for logic high for the control input (IN)
V _{IL}	Maximum input voltage for logic low for the control input (IN)
V _i	Voltage at the control input (IN)
I _{IH} , I _{IL}	Leakage current measured at the control input (IN)
t _{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.
t _{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.
t _{BBM}	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
Q _C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, Q _C = C _L × ΔV _{COM} , C _L is the load capacitance and ΔV _{COM} is the change in analog output voltage.
C _{NO(OFF)}	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
C _{NO(ON)}	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
C _{COM(ON)}	Capacitance at the COM port when the corresponding channel (COM to NO) is ON
C _{COM(OFF)}	Capacitance at the COM port when the corresponding channel (COM to NO) is OFF
C _i	Capacitance of control input (IN)
O _{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.
X _{TALK}	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain.
I ₊	Static power-supply current with the control (IN) pin at V ₊ or GND

PARAMETER MEASUREMENT INFORMATION

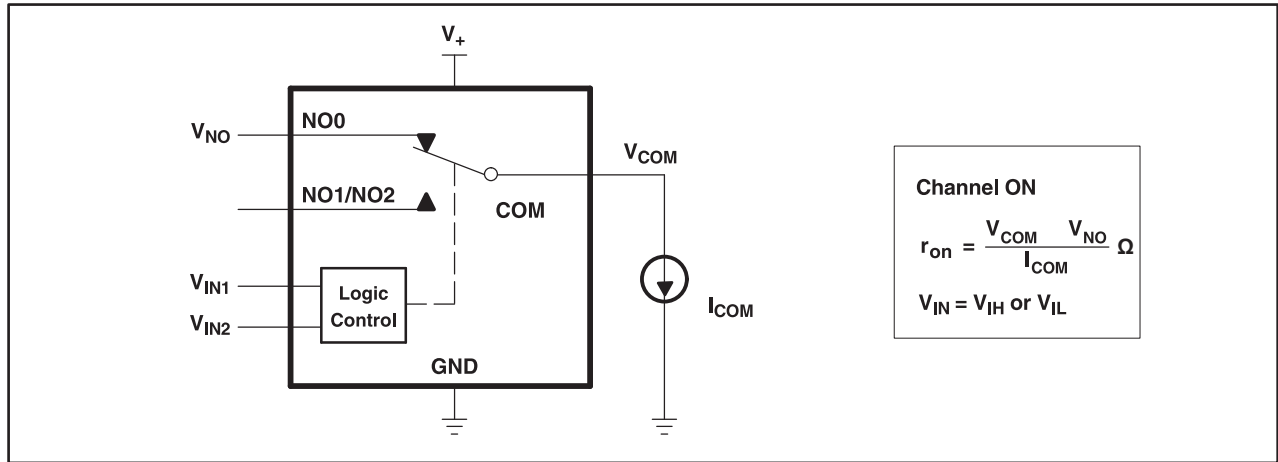


Figure 13. ON-State Resistance (r_{on})

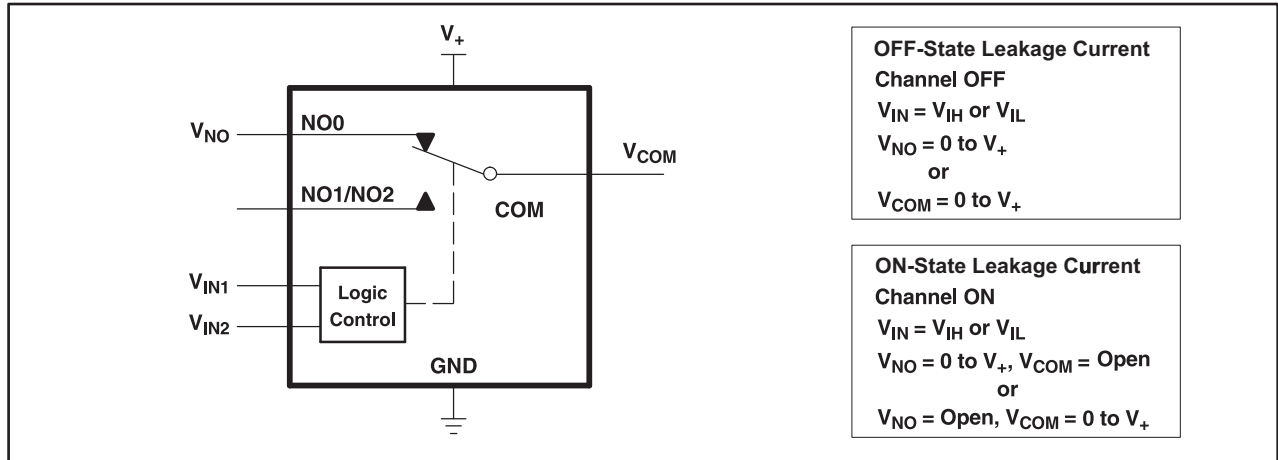


Figure 14. ON- and OFF-State Leakage Current ($I_{COM(ON)}$, $I_{COM(OFF)}$, $I_{NO(ON)}$, $I_{NO(OFF)}$)

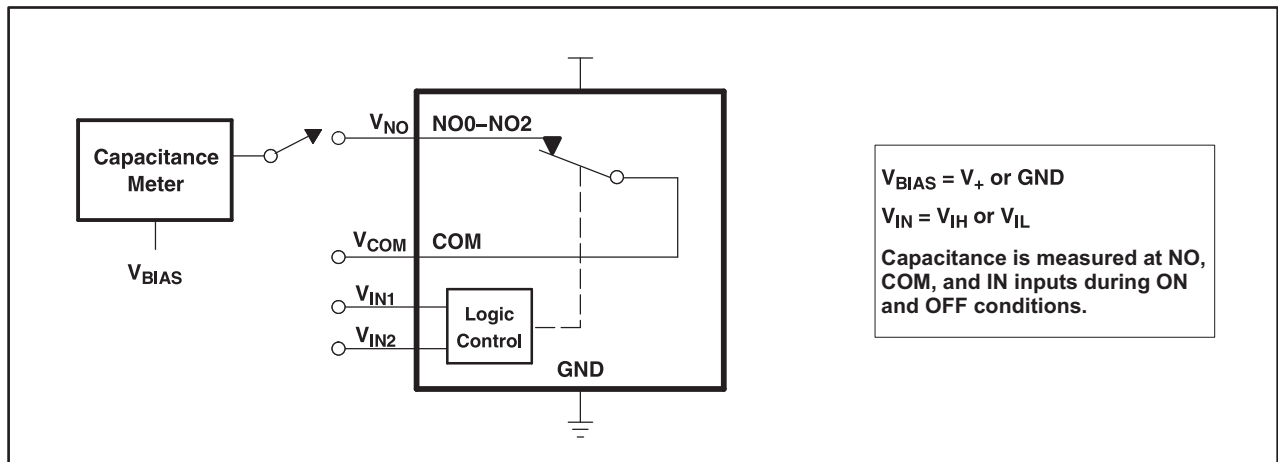


Figure 15. Capacitance (C_I , $C_{COM(ON)}$, $C_{NO(OFF)}$, $C_{COM(OFF)}$, $C_{NO(ON)}$)

- A. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- B. C_L includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION (continued)

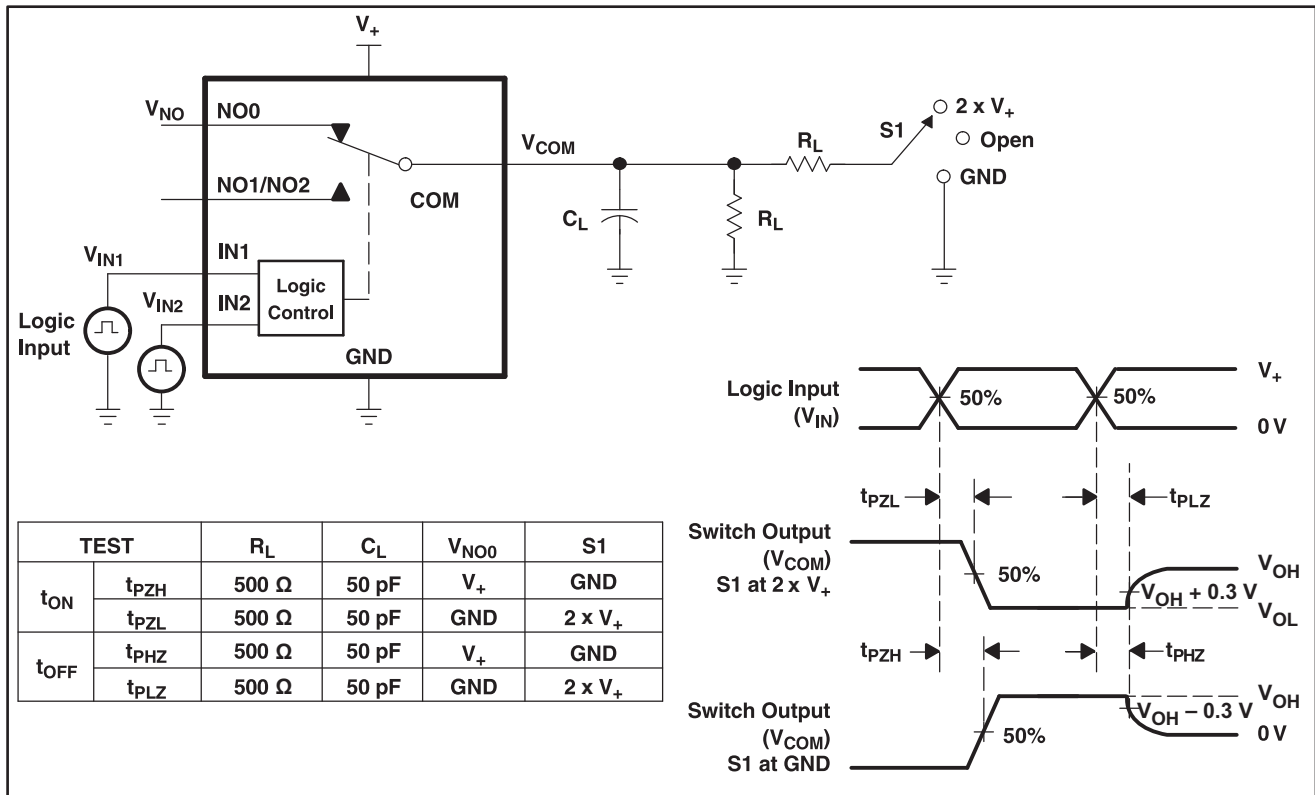


Figure 16. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.
- D. C_L includes probe and jig capacitance.

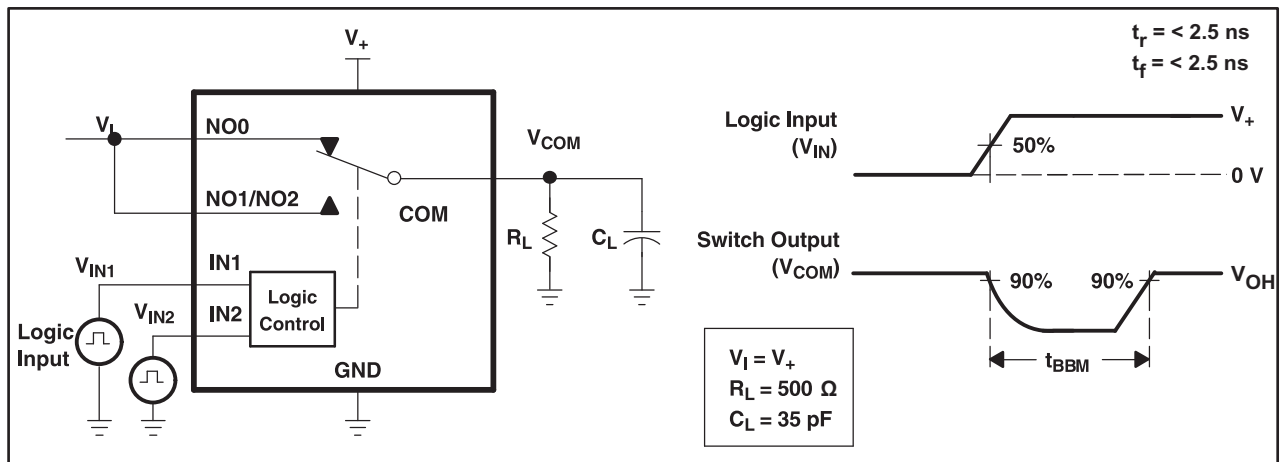


Figure 17. Break-Before-Make Time (t_{BBM})

PARAMETER MEASUREMENT INFORMATION (continued)

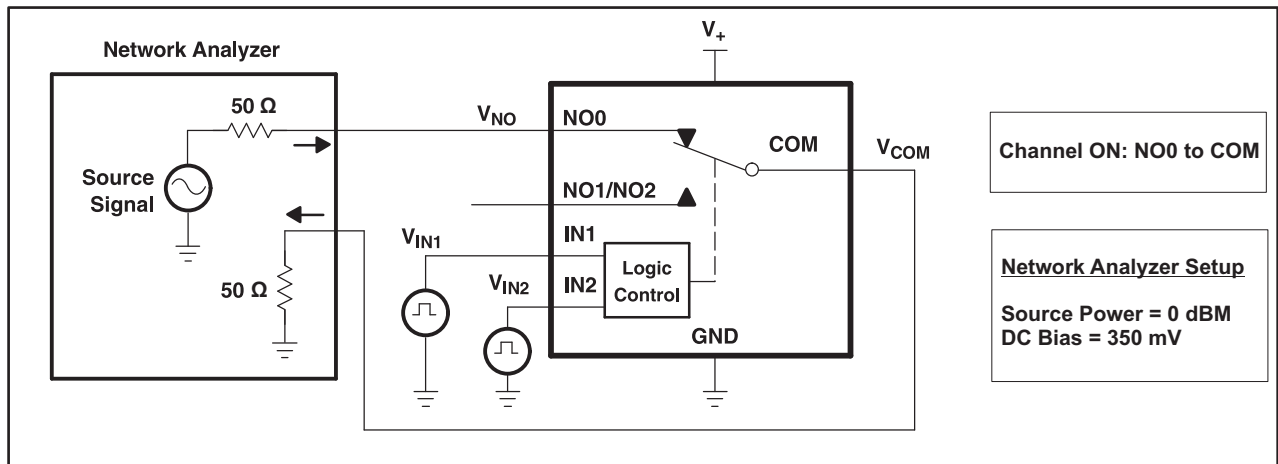


Figure 18. Bandwidth (BW)

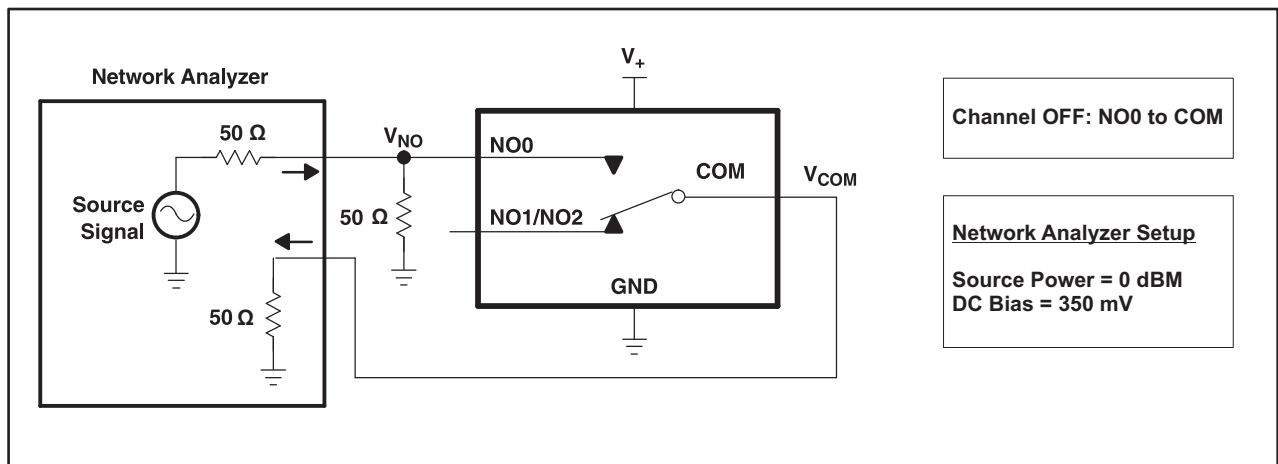


Figure 19. OFF Isolation (O_{ISO})

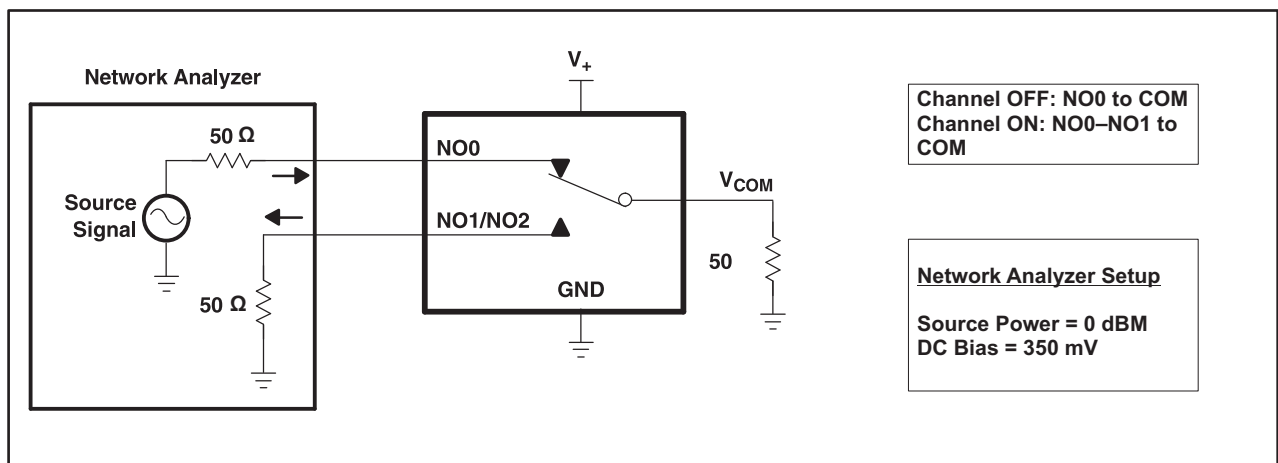


Figure 20. Crosstalk (X_{TALK})

- E. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_0 = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.
- F. C_L includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION (continued)

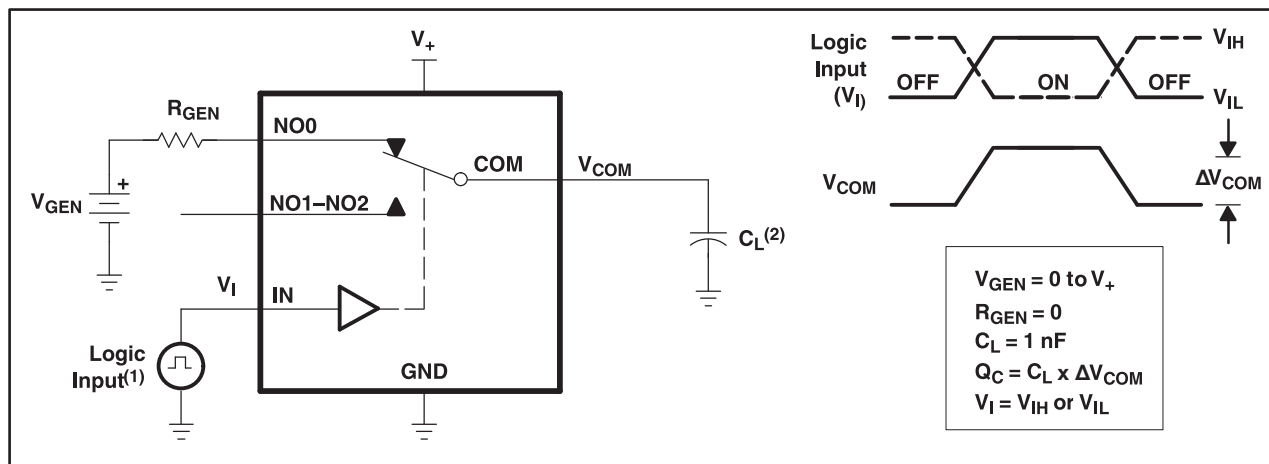


Figure 21. Charge Injection (Q_C)

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS5A3357QDCURQ1	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	JAVR
TS5A3357QDCURQ1.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	JAVR

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TS5A3357-Q1 :

- Catalog : [TS5A3357](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A3357QDCURQ1	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

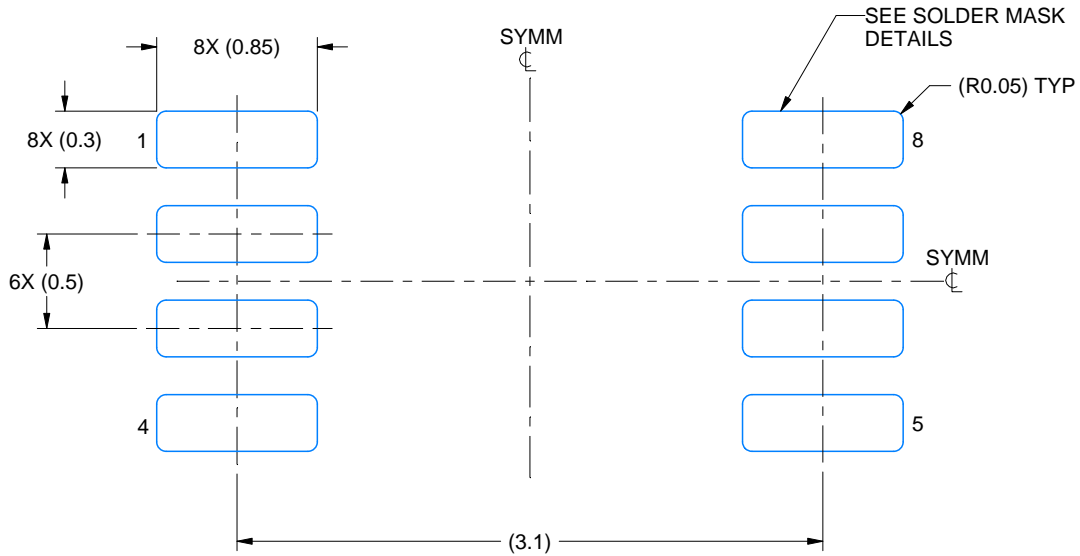
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A3357QDCURQ1	VSSOP	DCU	8	3000	202.0	201.0	28.0

EXAMPLE BOARD LAYOUT

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



4225266/A 09/2014

NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A 09/2014

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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